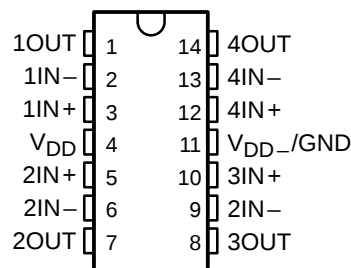


TLC254, TLC254A, TLC254B, TLC254Y, TLC25L4, TLC25L4A, TLC25L4B TLC25L4Y, TLC25M4, TLC25M4A, TLC25M4B, TLC25M4Y LinCMOS™ QUAD OPERATIONAL AMPLIFIERS

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- A-Suffix Versions Offer 5-mV V_{IO}
- B-Suffix Versions Offer 2-mV V_{IO}
- Wide Range of Supply Voltages
1.4 V to 16 V
- True Single-Supply Operation
- Common-Mode Input Voltage Includes the Negative Rail
- Low Noise . . . 25 nV/ $\sqrt{\text{Hz}}$ Typ at $f = 1 \text{ kHz}$
(High-Bias Version)

D, N, OR PW PACKAGE
(TOP VIEW)



description

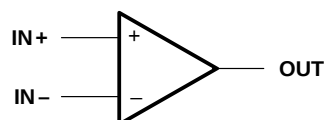
The TLC254, TLC254A, TLC254B, TLC25L4, TLC25L4A, TLC25L4B, TLC25M4, TLC25M4A and TLC25M4B are low-cost, low-power quad operational amplifiers designed to operate with single or dual supplies. These devices utilize the Texas Instruments silicon gate LinCMOS™

process, giving them stable input-offset voltages that are available in selected grades of 2, 5, or 10 mV maximum, very high input impedances, and extremely low input offset and bias currents. Because the input common-mode range extends to the negative rail and the power consumption is extremely low, this series is ideally suited for battery-powered or energy-conserving applications. The series offers operation down to a 1.4-V supply, is stable at unity gain, and has excellent noise characteristics.

These devices have internal electrostatic-discharge (ESD) protection circuits that prevent catastrophic failures at voltages up to 2000 V as tested under MIL-STD-883C, Method 3015.1. However, care should be exercised in handling these devices as exposure to ESD may result in degradation of the device parametric performance.

Because of the extremely high input impedance and low input bias and offset currents, applications for these devices include many areas that have previously been limited to BIFET and NFET product types. Any circuit using high-impedance elements and requiring small offset errors is a good candidate for cost-effective use of these devices. Many features associated with bipolar technology are available with LinCMOS operational amplifiers without the power penalties of traditional bipolar devices.

symbol (each amplifier)



Available options

T_A	V_{IOmax} AT 25°C	PACKAGED DEVICES			CHIP FORM (Y)
		SMALL OUTLINE (D)	PLASTIC DIP (N)	TSSOP (PW)	
0°C to 70°C	10 mV	TLC254CD	TLC254CN	TLC254CPW	TLC254Y
	5 mV	TLC254ACD	TLC254ACN	—	—
	2 mV	TLC254BCD	TLC254BCN	—	—
	10 mV	TLC25L4CD	TLC25L4CN	TLC25L4CPW	TLC25L4Y
	5 mV	TLC25L4ACD	TLC25L4ACN	—	—
	2 mV	TLC25L2BCD	TLC25L4BCN	—	—
	10 mV	TLC25M4CD	TLC25M4CN	TLC25M4CPW	TLC25M4Y
	5 mV	TLC25M4ACD	TLC25M4ACN	—	—
	2 mV	TLC25M4BCD	TLC25M4BCN	—	—

The D package is available taped and reeled. Add the suffix R to the device type (e.g., TLC254CDR). Chips are tested at 25°C.

LinCMOS is a trademark of Texas Instruments.

PRODUCTION DATA information is current as of publication date. Products conform to specifications per the terms of Texas Instruments standard warranty. Production processing does not necessarily include testing of all parameters.



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TLC254, TLC254A, TLC254B, TLC254Y, TLC25L4, TLC25L4A, TLC25L4B TLC25L4Y, TLC25M4, TLC25M4A, TLC25M4B, TLC25M4Y LinCMOS™ QUAD OPERATIONAL AMPLIFIERS

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description (continued)

General applications such as transducer interfacing, analog calculations, amplifier blocks, active filters, and signal buffering are all easily designed with these devices. Remote and inaccessible equipment applications are possible using their low-voltage and low-power capabilities. These devices are well suited to solve the difficult problems associated with single-battery and solar-cell-powered applications. This series includes devices that are characterized for the commercial temperature range and are available in 14-pin plastic dip and the small-outline packages. The device is also available in chip form.

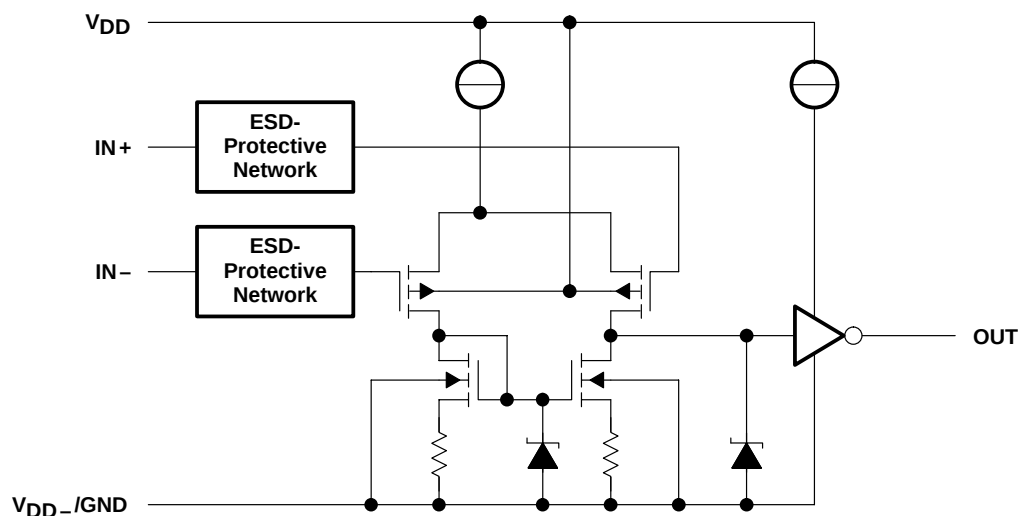
These devices are characterized for operation from 0°C to 70°C.

DEVICE FEATURES

PARAMETER	TLC25L4_C (LOW BIAS)	TLC25M4_C (MEDIUM BIAS)	TLC254_C (HIGH BIAS)
Supply current (Typ)	40 μ A	600 μ A	4000 μ A
Slew rate (Typ)	0.04 V/ μ A	0.6 V/ μ A	4.5 V/ μ A
Input offset voltage (Max)			
TLC254C, TLC25L4C, TLC25M4C	10 mV	10 mV	10 mV
TLC254AC, TLC25L4AC, TLC25M4AC	5 mV	5 mV	5 mV
TLC254BC, TLC25L4BC, TLC25M4BC	2 mV	2 mV	2 mV
Offset voltage drift (Typ)	0.1 μ V/month [†]	0.1 μ V/month [†]	0.1 μ V/month [†]
Offset voltage temperature coefficient (Typ)	0.7 μ V/°C	2 μ V/°C	5 μ V/°C
Input bias current (Typ)	1 pA	1 pA	1 pA
Input offset current (Typ)	1 pA	1 pA	1 pA

[†] The long-term drift value applies after the first month.

equivalent schematic (each amplifier)

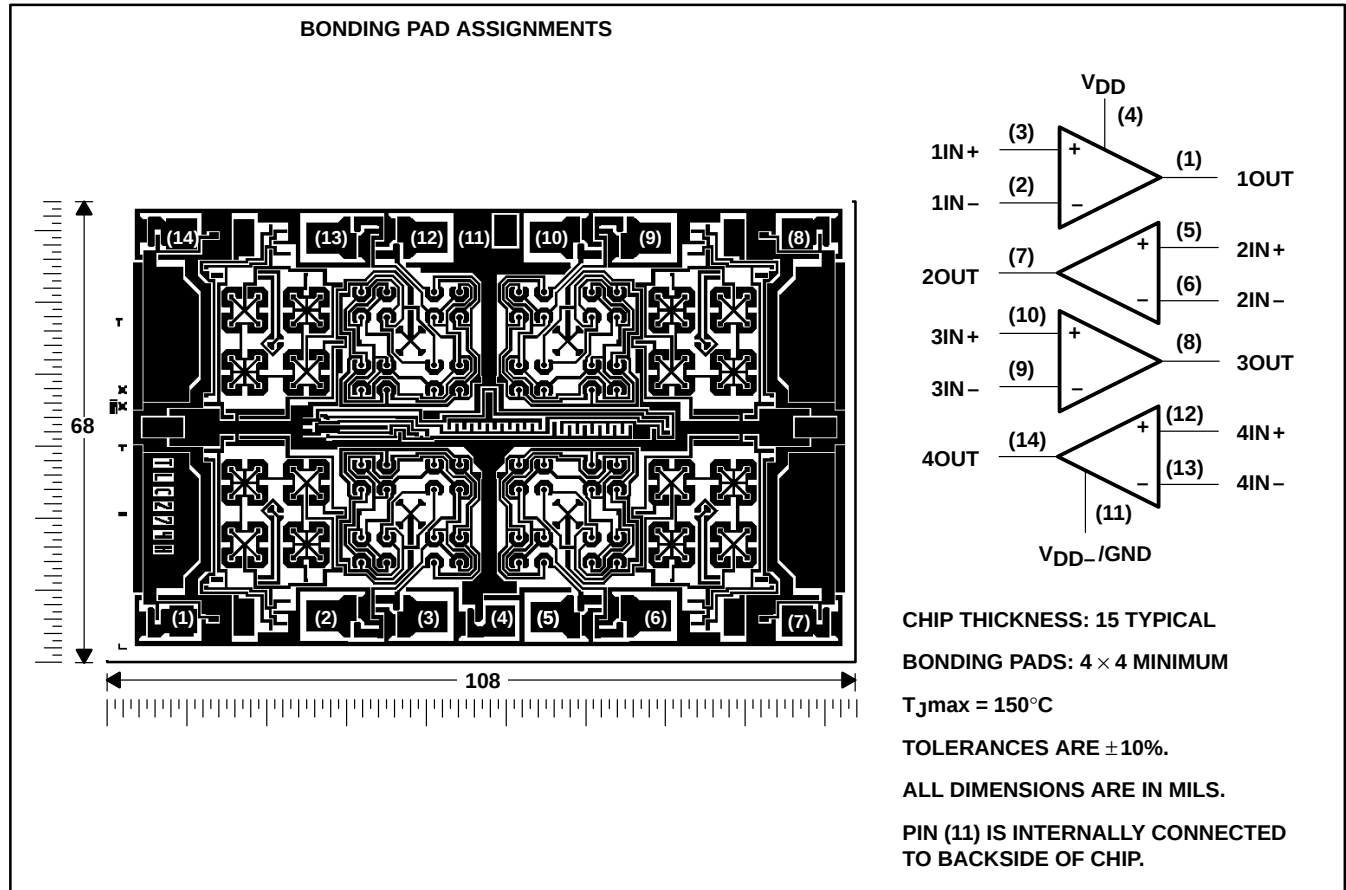


**TLC254, TLC254A, TLC254B, TLC254Y, TLC25L4, TLC25L4A, TLC25L4B
TLC25L4Y, TLC25M4, TLC25M4A, TLC25M4B, TLC25M4Y
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chip information

These chips, when properly assembled, display characteristics similar to the TLC25_4C. Thermal compression or ultrasonic bonding may be used on the doped-aluminum bonding pads. Chips may be mounted with conductive epoxy or a gold-silicon preform.



**TLC254, TLC254A, TLC254B, TLC254Y, TLC25L4, TLC25L4A, TLC25L4B
TLC25L4Y, TLC25M4, TLC25M4A, TLC25M4B, TLC25M4Y
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absolute maximum ratings over operating free-air temperature range (unless otherwise noted)[†]

Supply voltage, V_{DD} (see Note 1)	18 V
Differential input voltage (see Note 2)	± 18 V
Input voltage range (any input)	–0.3 V to 18 V
Duration of short-circuit at (or below) 25°C free-air temperature (see Note 3)	unlimited
Continuous total dissipation	See Dissipation Rating Table
Operating free-air temperature range	0°C to 70°C
Storage temperature range	–65°C to 150°C
Lead temperature 1,6 mm (1/16 inch) from case for 10 seconds	260°C

[†] Stresses beyond those listed under “absolute maximum ratings” may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under “recommended operating conditions” is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

- NOTES: 1. All voltage values, except differential voltages, are with respect to V_{DD-}/GND .
2. Differential voltages are at $IN+$, with respect to $IN-$.
3. The output may be shorted to either supply. Temperature and/or supply voltages must be limited to ensure the maximum dissipation rating is not exceeded.

DISSIPATION RATING TABLE

PACKAGE	$T_A \leq 25^\circ\text{C}$ POWER RATING	DERATING FACTOR ABOVE $T_A = 25^\circ\text{C}$	$T_A = 70^\circ\text{C}$ POWER RATING
D	725 mW	5.8 mW/°C	464 mW
N	1050 mW	9.2 mW/°C	736 mW
PW	700 mW	5.6 mW/°C	448 mW

recommended operating conditions

		MIN	MAX	UNIT
Supply voltage, V_{DD}		1.4	16	V
Common-mode input voltage, V_{IC}	$V_{DD} = 1.4$ V	0	0.2	V
	$V_{DD} = 5$ V	–0.2	4	
	$V_{DD} = 10$ V	–0.2	9	
	$V_{DD} = 16$ V	–0.2	14	
Operating free-air temperature, T_A		0	70	°C



electrical characteristics at specified free-air temperature, $V_{DD} = 1.4$ V (unless otherwise noted)

PARAMETER		TEST CONDITIONS†	T _A	TLC254_C			TLC25L4_C			TLC25M4_C			UNIT
				MIN	TYP	MAX	MIN	TYP	MAX	MIN	TYP	MAX	
V _{IO}	Input offset voltage	V _O = 0.2 V, R _S = 50 Ω	25°C	10			10			10			mV
			0°C to 70°C	12			12			12			
			25°C	5			5			5			
			0°C to 70°C	6.5			6.5			6.5			
			25°C	2			2			2			
			0°C to 70°C	3			3			3			
a _{VIO}	Average temperature coefficient of input offset voltage		25°C to 70°C	1			1			1			μV/°C
I _{IO}	Input offset current	V _O = 0.2 V	25°C	1	60	1	60	1	60	pA			
			0°C to 70°C	300			300						
I _{IB}	Input bias current	V _O = 0.2 V	25°C	1	60	1	60	1	60	pA			
			0°C to 70°C	600			600						
V _{ICR}	Common-mode input voltage range		25°C	0 to 0.2			0 to 0.2			0 to 0.2			V
V _{OM}	Peak output voltage swing‡	V _{ID} = 100 mV	25°C	450	700	450	700	450	700	mV			
A _{VD}	Large-signal differential voltage amplification	V _O = 100 to 300 mV, R _S = 50 Ω	25°C	10			20			20			V/mV
CMRR	Common-mode rejection ratio	V _O = 0.2 V, V _{IC} = V _{ICR} min	25°C	60	77	60	77	60	77	dB			
I _{DD}	Supply current	V _O = 0.2 V, No load	25°C	600 750			50 68			400 500			μA

† All characteristics are measured under open-loop conditions with zero common-mode input voltage unless otherwise specified. Unless otherwise noted, an output load resistor is connected from the output to ground and has the following value: for low bias, $R_L = 1$ M Ω , for medium bias $R_L = 100$ k Ω , and for high bias $R_L = 10$ k Ω .

‡ The output swings to the potential of V_{DD-}/GND .

operating characteristics, $V_{DD} = 1.4$ V, $T_A = 25^\circ\text{C}$

PARAMETER		TEST CONDITIONS	TLC254_C			TLC25L4_C			TLC25M4_C			UNIT
			MIN	TYP	MAX	MIN	TYP	MAX	MIN	TYP	MAX	
SR	Slew rate at unity gain	See Figure 1			0.1			0.001			0.01	V/ μ s
B_1	Unity-gain bandwidth	$A_V = 40$ dB, $C_L = 10$ pF, $R_S = 50$ Ω , See Figure 1			12			12			12	kHz
	Overshoot factor	See Figure 1			30%			35%			35%	

**TLC254, TLC254A, TLC254B, TLC254Y, TLC25L4, TLC25L4A, TLC25L4B
TLC25L4Y, TLC25M4, TLC25M4A, TLC25M4B, TLC25M4Y
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electrical characteristics at specified free-air temperature, $V_{DD} = 5\text{ V}$ (unless otherwise noted)

PARAMETER		TEST CONDITIONS		$T_A^\dagger$	TLC254, TLC254AC, TLC254BC			UNIT
					MIN	TYP	MAX	
V_{IO} Input offset voltage	TLC254C	$V_O = 1.4\text{ V}$, $R_S = 50\ \Omega$	$V_{IC} = 0$, $R_L = 10\text{ k}\Omega$	25°C		1.1	10	mV
				Full range			12	
	TLC254AC	$V_O = 1.4\text{ V}$, $R_S = 50\ \Omega$	$V_{IC} = 0$, $R_L = 10\text{ k}\Omega$	25°C		0.9	5	
				Full range			6.5	
	TLC254BC	$V_O = 1.4\text{ V}$, $R_S = 50\ \Omega$	$V_{IC} = 0$, $R_L = 10\text{ k}\Omega$	25°C		0.34	2	
				Full range			3	
α_{VIO} Average temperature coefficient of input offset voltage				25°C to 70°C		1.8		$\mu\text{V}/^\circ\text{C}$
I_{IO} Input offset current (see Note 4)		$V_O = 2.5\text{ V}$	$V_{IC} = 2.5\text{ V}$	25°C		0.1	60	pA
				70°C		7	300	
I_{IB} Input bias current (see Note 4)		$V_O = 2.5\text{ V}$	$V_{IC} = 2.5\text{ V}$	25°C		0.6	60	pA
				70°C		40	600	
V_{ICR} Common-mode input voltage range (see Note 5)				25°C	–0.2 to 4	–0.3 to 4.2		V
				Full range	–0.2 to 3.5			
V_{OH} High-level output voltage		$V_{ID} = 100\text{ mV}$	$R_L = 10\text{ k}\Omega$	0°C		3	3.8	V
				25°C		3.2	3.8	
				70°C		3	3.8	
V_{OL} Low-level output voltage		$V_{ID} = -100\text{ mV}$	$I_{OL} = 0$	0°C		0	50	mV
				25°C		0	50	
				70°C		0	50	
A_{VD} Large-signal differential voltage amplification		$V_O = 0.25\text{ V to }2\text{ V}$	$R_L = 10\text{ k}\Omega$	0°C		4	27	V/mV
				25°C		5	23	
				70°C		4	20	
CMRR Common-mode rejection ratio		$V_{IC} = V_{ICRmin}$		0°C		60	84	dB
				25°C		65	80	
				70°C		60	85	
k_{SVR} Supply-voltage rejection ratio ($\Delta V_{DD}/\Delta V_{IO}$)		$V_{DD} = 5\text{ V to }10\text{ V}$	$V_O = 1.4\text{ V}$	0°C		60	94	dB
				25°C		65	95	
				70°C		60	96	
I_{DD} Supply current (four amplifiers)		$V_O = 2.5\text{ V}$, No load	$V_{IC} = 2.5\text{ V}$	0°C		3.1	7.2	mA
				25°C		2.7	6.4	
				70°C		2.3	5.2	

† Full range is 0°C to 70°C.

NOTES: 4. The typical values of input bias current and input offset current below 5 pA were determined mathematically.

5. This range also applies to each input individually.



**TLC254, TLC254A, TLC254B, TLC254Y, TLC25L4, TLC25L4A, TLC25L4B
TLC25L4Y, TLC25M4, TLC25M4A, TLC25M4B, TLC25M4Y
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electrical characteristics at specified free-air temperature, $V_{DD} = 10$ V (unless otherwise noted)

PARAMETER		TEST CONDITIONS		T _A [†]	TLC254C, TLC254AC, TLC254BC			UNIT
					MIN	TYP	MAX	
V _{IO}	Input offset voltage	TLC254C	V _O = 1.4 V, R _S = 50 Ω, V _{IC} = 0, R _L = 10 kΩ	25°C	1.1	10	mV	
				Full range	12			
		TLC254AC	V _O = 1.4 V, R _S = 50 Ω, V _{IC} = 0, R _L = 10 kΩ	25°C	0.9	5		
				Full range	6.5			
		TLC254BC	V _O = 1.4 V, R _S = 50 Ω, V _{IC} = 0, R _L = 10 kΩ	25°C	0.39	2		
				Full range	3			
°V _{IO}	Average temperature coefficient of input offset voltage			25°C to 70°C	2		μV/°C	
I _{IO}	Input offset current (see Note 4)	V _O = 5 V,	V _{IC} = 5 V	25°C	0.1	60	pA	
				70°C	7	300		
I _{IB}	Input bias current (see Note 4)	V _O = 5 V,	V _{IC} = 5 V	25°C	0.7	60	pA	
				70°C	50	600		
V _{ICR}	Common-mode input voltage range (see Note 5)			25°C	−0.2 to 9	−0.3 to 9.2	V	
				Full range	−0.2 to 8.5			
V _{OH}	High-level output voltage	V _{ID} = 100 mV,	R _L = 10 kΩ	0°C	7.8	8.5	V	
				25°C	8	8.5		
				70°C	7.8	8.4		
V _{OL}	Low-level output voltage	V _{ID} = −100 mV,	I _{OL} = 0	0°C	0	50	mV	
				25°C	0	50		
				70°C	0	50		
A _{VD}	Large-signal differential voltage amplification	V _O = 1 V to 6 V,	R _L = 10 kΩ	0°C	7.5	42	V/mV	
				25°C	10	36		
				70°C	7.5	32		
CMRR	Common-mode rejection ratio	V _{IC} = V _{ICRmin}		0°C	60	88	dB	
				25°C	65	85		
				70°C	60	88		
k _{SVR}	Supply-voltage rejection ratio (ΔV _{DD} /ΔV _{IO})	V _{DD} = 5 V to 10 V, V _O = 1.4 V		0°C	60	94	dB	
				25°C	65	95		
				70°C	60	96		
I _{DD}	Supply current (four amplifiers)	V _O = 5 V, No load	V _{IC} = 5 V,	0°C	4.5	8.8	mA	
				25°C	3.8	8		
				70°C	3.2	6.8		

† Full range is 0°C to 70°C.

NOTES: 4. The typical values of input bias current and input offset current below 5 pA were determined mathematically.

5. This range also applies to each input individually.



**TLC254, TLC254A, TLC254B, TLC254Y, TLC25L4, TLC25L4A, TLC25L4B
TLC25L4Y, TLC25M4, TLC25M4A, TLC25M4B, TLC25M4Y
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operating characteristics, $V_{DD} = 5\text{ V}$

PARAMETER	TEST CONDITIONS	T_A	TLC254C, TLC254AC, TLC254BC			UNIT
			MIN	TYP	MAX	
SR Slew rate at unity gain	$R_L = 10\text{ k}\Omega$, $C_L = 20\text{ pF}$, See Figure 1	$V_{I(PP)} = 1\text{ V}$	0°C	4		V/ μ s
			25°C	3.6		
			70°C	3		
		$V_{I(PP)} = 2.5\text{ V}$	0°C	3.1		
			25°C	2.9		
			70°C	2.5		
V_n Equivalent input noise voltage	$f = 1\text{ kHz}$, $R_S = 20\text{ }\Omega$, See Figure 2	25°C		25		nV/ $\sqrt{\text{Hz}}$
B_{OM} Maximum output-swing bandwidth	$V_O = V_{OH}$, See Figure 1	$C_L = 20\text{ pF}$, $R_L = 10\text{ k}\Omega$	0°C	340		kHz
			25°C	320		
			70°C	260		
B_1 Unity-gain bandwidth	$V_I = 10\text{ mV}$, $C_L = 20\text{ pF}$, See Figure 1		0°C	2		MHz
			25°C	1.7		
			70°C	1.3		
ϕ_m Phase margin	$V_I = 10\text{ mV}$, See Figure 3	$f = B_1$, $C_L = 20\text{ pF}$	0°C	47°		
			25°C	46°		
			70°C	43°		

operating characteristics, $V_{DD} = 10\text{ V}$

PARAMETER	TEST CONDITIONS	T_A	TLC254C, TLC254AC, TLC254BC			UNIT
			MIN	TYP	MAX	
SR Slew rate at unity gain	$R_L = 10\text{ k}\Omega$, $C_L = 20\text{ pF}$, See Figure 1	$V_{I(PP)} = 1\text{ V}$	0°C	5.9		V/ μ s
			25°C	5.3		
			70°C	4.3		
		$V_{I(PP)} = 5.5\text{ V}$	0°C	5.1		
			25°C	4.6		
			70°C	3.8		
V_n Equivalent input noise voltage	$f = 1\text{ kHz}$, $R_S = 20\text{ }\Omega$, See Figure 2	25°C		25		nV/ $\sqrt{\text{Hz}}$
B_{OM} Maximum output-swing bandwidth	$V_O = V_{OH}$, See Figure 1	$C_L = 20\text{ pF}$, $R_L = 10\text{ k}\Omega$	0°C	220		kHz
			25°C	200		
			70°C	140		
B_1 Unity-gain bandwidth	$V_I = 10\text{ mV}$, $C_L = 20\text{ pF}$, See Figure 1		0°C	2.5		MHz
			25°C	2.2		
			70°C	1.8		
ϕ_m Phase margin	$V_I = 10\text{ mV}$, See Figure 3	$f = B_1$, $C_L = 20\text{ pF}$	0°C	50°		
			25°C	49°		
			70°C	46°		

**TLC254, TLC254A, TLC254B, TLC254Y, TLC25L4, TLC25L4A, TLC25L4B
TLC25L4Y, TLC25M4, TLC25M4A, TLC25M4B, TLC25M4Y
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electrical characteristics at specified free-air temperature, $V_{DD} = 5\text{ V}$ (unless otherwise noted)

PARAMETER		TEST CONDITIONS		T _A [†]	TLC25L4C TLC25L4AC TLC25L4BC			UNIT
					MIN	TYP	MAX	
V _{IO}	Input offset voltage	TLC25L4C	V _O = 1.4 V, R _S = 50 Ω,	V _{IC} = 0, R _L = 1 MΩ	25°C	1.1	10	mV
					Full range		12	
		TLC25L4AC	V _O = 1.4 V, R _S = 50 Ω,	V _{IC} = 0, R _L = 1 MΩ	25°C	0.9	5	
					Full range		6.5	
		TLC25L4BC	V _O = 1.4 V, R _S = 50 Ω,	V _{IC} = 0, R _L = 1 MΩ	25°C	0.24	2	
					Full range		3	
°V _{IO}	Average temperature coefficient of input offset voltage			25°C to 70°C	1.1		μV/°C	
I _{IO}	Input offset current (see Note 4)	V _O = 2.5 V,	V _{IC} = 2.5 V	25°C	0.1	60	pA	
				70°C	7	300		
I _{IB}	Input bias current (see Note 4)	V _O = 2.5 V,	V _{IC} = 2.5 V	25°C	0.6	60	pA	
				70°C	40	600		
V _{ICR}	Common-mode input voltage range (see Note 5)			25°C	−0.2 to 4	−0.3 to 4.2	V	
				Full range	−0.2 to 3.5		V	
V _{OH}	High-level output voltage	V _{ID} = 100 mV,	R _L = 1 MΩ	0°C	3	4.1	V	
				25°C	3.2	4.1		
				70°C	3	4.2		
V _{OL}	Low-level output voltage	V _{ID} = −100 mV,	I _{OL} = 0	0°C	0	50	mV	
				25°C	0	50		
				70°C	0	50		
A _{VD}	Large-signal differential voltage amplification	V _O = 0.25 V to 2 V, R _L = 1 MΩ		0°C	50	680	V/mV	
				25°C	50	520		
				70°C	50	380		
CMRR	Common-mode rejection ratio	V _{IC} = V _{ICRmin}		0°C	60	95	dB	
				25°C	65	94		
				70°C	60	95		
k _{SVR}	Supply-voltage rejection ratio (ΔV _{DD} /ΔV _{IO})	V _{DD} = 5 V to 10 V, V _O = 1.4 V		0°C	60	97	dB	
				25°C	70	98		
				70°C	60	97		
I _{DD}	Supply current (four amplifiers)	V _O = 2.5 V, No load	V _{IC} = 2.5 V,	0°C	48	84	μA	
				25°C	40	68		
				70°C	31	56		

† Full range is 0°C to 70°C.

NOTES: 4. The typical values of input bias current and input offset current below 5 pA were determined mathematically.

5. This range also applies to each input individually.



**TLC254, TLC254A, TLC254B, TLC254Y, TLC25L4, TLC25L4A, TLC25L4B
TLC25L4Y, TLC25M4, TLC25M4A, TLC25M4B, TLC25M4Y
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electrical characteristics at specified free-air temperature, $V_{DD} = 10\text{ V}$ (unless otherwise noted)

PARAMETER		TEST CONDITIONS		T _A [†]	TLC25L4C TLC25L4AC TLC25L4BC			UNIT
					MIN	TYP	MAX	
V _{IO}	Input offset voltage	TLC25L4C	V _O = 1.4 V, R _S = 50 Ω, V _{IC} = 0, R _L = 1 MΩ	25°C	1.1	10	mV	
				Full range		12		
		TLC25L4AC	V _O = 1.4 V, R _S = 50 Ω, V _{IC} = 0, R _L = 1 MΩ	25°C	0.9	5		
				Full range		6.5		
		TLC25L4BC	V _O = 1.4 V, R _S = 50 Ω, V _{IC} = 0, R _L = 1 MΩ	25°C	0.26	2		
				Full range		3		
α _{VIO}	Average temperature coefficient of input offset voltage			25°C to 70°C	1		μV/°C	
I _{IO}	Input offset current (see Note 4)	V _O = 5 V, V _{IC} = 5 V		25°C	0.1	60	pA	
				70°C	7	300		
I _{IB}	Input bias current (see Note 4)	V _O = 5 V, V _{IC} = 5 V		25°C	0.7	60	pA	
				70°C	50	600		
V _{ICR}	Common-mode input voltage range (see Note 5)			25°C	−0.2 to 9	−0.3 to 9.2	V	
				Full range	−0.2 to 8.5		V	
V _{OH}	High-level output voltage	V _{ID} = 100 mV, R _L = 1 MΩ		0°C	7.8	8.9	V	
				25°C	8	8.9		
				70°C	7.8	8.9		
V _{OL}	Low-level output voltage	V _{ID} = −100 mV, I _{OL} = 0		0°C	0	50	mV	
				25°C	0	50		
				70°C	0	50		
A _{VD}	Large-signal differential voltage amplification	V _O = 1 V to 6 V, R _L = 1 MΩ		0°C	50	1025	V/mV	
				25°C	50	870		
				70°C	50	660		
CMRR	Common-mode rejection ratio	V _{IC} = V _{ICRmin}		0°C	60	97	dB	
				25°C	65	97		
				70°C	60	97		
k _{SVR}	Supply-voltage rejection ratio (ΔV _{DD} /ΔV _{IO})	V _{DD} = 5 V to 10 V, V _O = 1.4 V		0°C	60	97	dB	
				25°C	70	97		
				70°C	60	98		
I _{DD}	Supply current (four amplifiers)	V _O = 5 V, No load V _{IC} = 5 V,		0°C	72	132	μA	
				25°C	57	92		
				70°C	44	80		

† Full range is 0°C to 70°C.

NOTES: 4. The typical values of input bias current and input offset current below 5 pA were determined mathematically.

5. This range also applies to each input individually.



**TLC254, TLC254A, TLC254B, TLC254Y, TLC25L4, TLC25L4A, TLC25L4B
TLC25L4Y, TLC25M4, TLC25M4A, TLC25M4B, TLC25M4Y
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operating characteristics, $V_{DD} = 5\text{ V}$

PARAMETER	TEST CONDITIONS	T_A	TLC25L4C TLC25L4AC TLC25L4BC			UNIT
			MIN	TYP	MAX	
SR Slew rate at unity gain	$R_L = 1\text{ M}\Omega$, See Figure 1 $C_L = 20\text{ pF}$	$V_{I(PP)} = 1\text{ V}$	0°C	0.04		V/ μ s
			25°C	0.03		
			70°C	0.03		
		$V_{I(PP)} = 2.5\text{ V}$	0°C	0.03		
			25°C	0.03		
			70°C	0.02		
V_n Equivalent input noise voltage	$f = 1\text{ kHz}$, $R_S = 20\text{ }\Omega$, See Figure 2	25°C		70		nV/ $\sqrt{\text{Hz}}$
B_{OM} Maximum output-swing bandwidth	$V_O = V_{OH}$, See Figure 1 $C_L = 20\text{ pF}$, $R_L = 1\text{ M}\Omega$,	0°C		6		kHz
		25°C		5		
		70°C		4.5		
B_1 Unity-gain bandwidth	$V_I = 10\text{ mV}$, $C_L = 20\text{ pF}$, See Figure 1	0°C		100		kHz
		25°C		85		
		70°C		65		
ϕ_m Phase margin	$V_I = 10\text{ mV}$, See Figure 3 $f = B_1$, $C_L = 20\text{ pF}$,	0°C		36°		
		25°C		34°		
		70°C		30°		

operating characteristics, $V_{DD} = 10\text{ V}$

PARAMETER	TEST CONDITIONS	T_A	TLC25L4C TLC25L4AC TLC25L4BC			UNIT
			MIN	TYP	MAX	
SR Slew rate at unity gain	$R_L = 1\text{ M}\Omega$, See Figure 1 $C_L = 20\text{ pF}$	$V_{I(PP)} = 1\text{ V}$	0°C	0.05		V/ μ s
			25°C	0.05		
			70°C	0.04		
		$V_{I(PP)} = 5.5\text{ V}$	0°C	0.05		
			25°C	0.04		
			70°C	0.04		
V_n Equivalent input noise voltage	$f = 1\text{ kHz}$, $R_S = 20\text{ }\Omega$, See Figure 2	25°C		70		nV/ $\sqrt{\text{Hz}}$
B_{OM} Maximum output-swing bandwidth	$V_O = V_{OH}$, See Figure 1 $C_L = 20\text{ pF}$, $R_L = 1\text{ M}\Omega$,	0°C		1.3		kHz
		25°C		1		
		70°C		0.9		
B_1 Unity-gain bandwidth	$V_I = 10\text{ mV}$, $C_L = 20\text{ pF}$, See Figure 1	0°C		125		kHz
		25°C		110		
		70°C		90		
ϕ_m Phase margin	$V_I = 10\text{ mV}$, See Figure 3 $f = B_1$, $C_L = 20\text{ pF}$,	0°C		40°		
		25°C		38°		
		70°C		34°		



TLC254, TLC254A, TLC254B, TLC254Y, TLC25L4, TLC25L4A, TLC25L4B
TLC25L4Y, TLC25M4, TLC25M4A, TLC25M4B, TLC25M4Y
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electrical characteristics at specified free-air temperature, $V_{DD} = 5\text{ V}$ (unless otherwise noted)

PARAMETER		TEST CONDITIONS		T _A [†]	TLC25M4C TLC25M4AC TLC25M4BC			UNIT
					MIN	TYP	MAX	
V _{IO}	Input offset voltage	TLC25M4C	V _O = 1.4 V, R _S = 50 Ω,	V _{IC} = 0, R _L = 100 kΩ	25°C	1.1	10	mV
					Full range		12	
		TLC25M4AC	V _O = 1.4 V, R _S = 50 Ω,	V _{IC} = 0, R _L = 100 kΩ	25°C	0.9	5	
					Full range		6.5	
		TLC25M4BC	V _O = 1.4 V, R _S = 50 Ω,	V _{IC} = 0, R _L = 100 kΩ	25°C	0.25	2	
					Full range		3	
°V _{IO}	Average temperature coefficient of input offset voltage			25°C to 70°C	1.7		μV/°C	
I _{IO}	Input offset current (see Note 4)		V _O = 2.5 V,	V _{IC} = 2.5 V	25°C	0.1	60	pA
					70°C	7	300	
I _{IB}	Input bias current (see Note 4)		V _O = 2.5 V,	V _{IC} = 2.5 V	25°C	0.6	60	pA
					70°C	40	600	
V _{ICR}	Common-mode input voltage range (see Note 5)				25°C	−0.2 to 4	−0.3 to 4.2	V
					Full range	−0.2 to 3.5		V
V _{OH}	High-level output voltage		V _{ID} = 100 mV,	R _L = 100 kΩ	0°C	3	3.9	V
					25°C	3.2	3.9	
					70°C	3	4	
V _{OL}	Low-level output voltage		V _{ID} = −100 mV,	I _{OL} = 0	0°C	0	50	mV
					25°C	0	50	
					70°C	0	50	
A _{VD}	Large-signal differential voltage amplification		V _O = 0.25 V to 2 V,	R _L = 100 kΩ	0°C	15	200	V/mV
					25°C	25	170	
					70°C	15	140	
CMRR	Common-mode rejection ratio		V _{IC} = V _{ICRmin}		0°C	60	91	dB
					25°C	65	91	
					70°C	60	92	
k _{SVR}	Supply-voltage rejection ratio (ΔV _{DD} /ΔV _{IO})		V _{DD} = 5 V to 10 V,	V _O = 1.4 V	0°C	60	92	dB
					25°C	70	93	
					70°C	60	94	
I _{DD}	Supply current (four amplifiers)		V _O = 2.5 V, No load	V _{IC} = 2.5 V,	0°C	500	1280	μA
					25°C	420	1120	
					70°C	340	880	

† Full range is 0°C to 70°C.

NOTES: 4. The typical values of input bias current and input offset current below 5 pA were determined mathematically.

5. This range also applies to each input individually.



**TLC254, TLC254A, TLC254B, TLC254Y, TLC25L4, TLC25L4A, TLC25L4B
TLC25L4Y, TLC25M4, TLC25M4A, TLC25M4B, TLC25M4Y
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electrical characteristics at specified free-air temperature, $V_{DD} = 10\text{ V}$ (unless otherwise noted)

PARAMETER		TEST CONDITIONS		$T_A^\dagger$	TLC25M4C TLC25M4AC TLC25M4BC			UNIT
					MIN	TYP	MAX	
V_{IO}	Input offset voltage	TLC25M4C	$V_O = 1.4\text{ V}$, $R_S = 50\ \Omega$, $V_{IC} = 0$, $R_L = 100\text{ k}\Omega$	25°C		1.1	10	mV
				Full range			12	
		TLC25M4AC	$V_O = 1.4\text{ V}$, $R_S = 50\ \Omega$, $V_{IC} = 0$, $R_L = 100\text{ k}\Omega$	25°C		0.9	5	
				Full range			6.5	
		TLC25M4BC	$V_O = 1.4\text{ V}$, $R_S = 50\ \Omega$, $V_{IC} = 0$, $R_L = 100\text{ k}\Omega$	25°C		0.26	2	
				Full range			3	
α_{VIO}	Average temperature coefficient of input offset voltage			25°C to 70°C		2.1		$\mu\text{V}/^\circ\text{C}$
I_{IO}	Input offset current (see Note 4)	$V_O = 5\text{ V}$, $V_{IC} = 5\text{ V}$		25°C		0.1	60	pA
				70°C		7	300	
I_{IB}	Input bias current (see Note 4)	$V_O = 5\text{ V}$, $V_{IC} = 5\text{ V}$		25°C		0.7	60	pA
				70°C		50	600	
V_{ICR}	Common-mode input voltage range (see Note 5)			25°C		–0.2 to 9	–0.3 to 9.2	V
				Full range		–0.2 to 8.5		V
V_{OH}	High-level output voltage	$V_{ID} = 100\text{ mV}$, $R_L = 100\text{ k}\Omega$		0°C		7.8	8.7	V
				25°C		8	8.7	
				70°C		7.8	8.7	
V_{OL}	Low-level output voltage	$V_{ID} = -100\text{ mV}$, $I_{OL} = 0$		0°C		0	50	mV
				25°C		0	50	
				70°C		0	50	
A_{VD}	Large-signal differential voltage amplification	$V_O = 1\text{ V to }6\text{ V}$, $R_L = 100\text{ k}\Omega$		0°C		15	320	V/mV
				25°C		25	275	
				70°C		15	230	
CMRR	Common-mode rejection ratio	$V_{IC} = V_{ICRmin}$		0°C		60	94	dB
				25°C		65	94	
				70°C		60	94	
k_{SVR}	Supply-voltage rejection ratio ($\Delta V_{DD}/\Delta V_{IO}$)	$V_{DD} = 5\text{ V to }10\text{ V}$, $V_O = 1.4\text{ V}$		0°C		60	92	dB
				25°C		70	93	
				70°C		60	94	
I_{DD}	Supply current (four amplifiers)	$V_O = 5\text{ V}$, No load $V_{IC} = 5\text{ V}$		0°C		690	1600	μA
				25°C		570	1200	
				70°C		440	1120	

† Full range is 0°C to 70°C.

NOTES: 4. The typical values of input bias current and input offset current below 5 pA were determined mathematically.

5. This range also applies to each input individually.



**TLC254, TLC254A, TLC254B, TLC254Y, TLC25L4, TLC25L4A, TLC25L4B
TLC25L4Y, TLC25M4, TLC25M4A, TLC25M4B, TLC25M4Y
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operating characteristics, $V_{DD} = 5\text{ V}$

PARAMETER	TEST CONDITIONS	T_A	TLC25M4C TLC25M4AC TLC25M4BC			UNIT
			MIN	TYP	MAX	
SR Slew rate at unity gain	$R_L = 100\text{ k}\Omega$, See Figure 1 $C_L = 20\text{ pF}$	$V_{I(PP)} = 1\text{ V}$	0°C	0.46		V/ μs
			25°C	0.43		V/ μs
			70°C	0.36		
		$V_{I(PP)} = 2.5\text{ V}$	0°C	0.43		V/ μs
			25°C	0.40		
			70°C	0.34		
V_n Equivalent input noise voltage	$f = 1\text{ kHz}$, $R_S = 20\text{ }\Omega$, See Figure 2	25°C		32		nV/ $\sqrt{\text{Hz}}$
B_{OM} Maximum output-swing bandwidth	$V_O = V_{OH}$, See Figure 1 $C_L = 20\text{ pF}$, $R_L = 100\text{ k}\Omega$,	0°C		60		kHz
		25°C		55		
		70°C		50		
B_1 Unity-gain bandwidth	$V_I = 10\text{ mV}$, $C_L = 20\text{ pF}$, See Figure 1	0°C		610		kHz
		25°C		525		
		70°C		400		
ϕ_m Phase margin	$V_I = 10\text{ mV}$, See Figure 3 $f = B_1$, $C_L = 20\text{ pF}$,	0°C		41°		
		25°C		40°		
		70°C		39°		

operating characteristics, $V_{DD} = 10\text{ V}$

PARAMETER	TEST CONDITIONS	T_A	TLC25M4C TLC25M4AC TLC25M4BC			UNIT
			MIN	TYP	MAX	
SR Slew rate at unity gain	$R_L = 100\text{ k}\Omega$, See Figure 1 $C_L = 20\text{ pF}$	$V_{I(PP)} = 1\text{ V}$	0°C	0.67		V/ μs
			25°C	0.62		
			70°C	0.51		
		$V_{I(PP)} = 5.5\text{ V}$	0°C	0.61		
			25°C	0.56		
			70°C	0.46		
V_n Equivalent input noise voltage	$f = 1\text{ kHz}$, $R_S = 20\text{ }\Omega$, See Figure 2	25°C		32		nV/ $\sqrt{\text{Hz}}$
B_{OM} Maximum output-swing bandwidth	$V_O = V_{OH}$, See Figure 1 $C_L = 20\text{ pF}$, $R_L = 100\text{ k}\Omega$,	0°C		40		kHz
		25°C		35		
		70°C		30		
B_1 Unity-gain bandwidth	$V_I = 10\text{ mV}$, $C_L = 20\text{ pF}$, See Figure 1	0°C		710		kHz
		25°C		635		
		70°C		510		
ϕ_m Phase margin	$V_I = 10\text{ mV}$, See Figure 3 $f = B_1$, $C_L = 20\text{ pF}$,	0°C		44°		
		25°C		43°		
		70°C		42°		



**TLC254, TLC254A, TLC254B, TLC254Y, TLC25L4, TLC25L4A, TLC25L4B
TLC25L4Y, TLC25M4, TLC25M4A, TLC25M4B, TLC25M4Y
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electrical characteristics, $V_{DD} = 5\text{ V}$, $T_A = 25^\circ\text{C}$ (unless otherwise noted)

PARAMETER	TEST CONDITIONS	TLC254Y			TLC25L4Y			TLC25M4Y			UNIT
		MIN	TYP	MAX	MIN	TYP	MAX	MIN	TYP	MAX	
V_{IO} Input offset voltage	$V_O = 1.4\text{ V}$, $V_{IC} = 0\text{ V}$, $R_S = 50\ \Omega$, See Note 6		1.1	10		1.1	10		1.1	10	mV
α_{VIO} Average temperature coefficient of input offset voltage			1.8			1.1			1.7		$\mu\text{V}/^\circ\text{C}$
I_{IO} Input offset current (see Note 4)	$V_O = V_{DD}/2$, $V_{IC} = V_{DD}/2$		0.1	60		0.1	60		0.1	60	pA
I_{IB} Input bias current (see Note 4)	$V_O = V_{DD}/2$, $V_{IC} = V_{DD}/2$		0.6	60		0.6	60		0.6	60	pA
V_{ICR} Common-mode input voltage range (see Note 5)		–0.2 to 4	–0.3 to 4.2		–0.2 to 4	–0.3 to 4.2		–0.2 to 4	–0.3 to 4.2		V
V_{OH} High-level output voltage	$V_{ID} = 100\text{ mV}$, $R_L = 100\text{ k}\Omega$	3.2	3.8		3.2	4.1		3.2	3.9		V
V_{OL} Low-level output voltage	$V_{ID} = -100\text{ mV}$, $I_{OL} = 0$		0	50		0	50		0	50	mV
A_{VD} Large-signal differential voltage amplification	$V_O = 0.25\text{ V}$, See Note 6	5	23		50	520		25	170		V/mV
CMRR Common-mode rejection ratio	$V_{IC} = V_{ICRmin}$	65	80		65	94		65	91		dB
k_{SVR} Supply-voltage rejection ratio ($\Delta V_{DD}/\Delta V_{IO}$)	$V_{DD} = 5\text{ V to }10\text{ V}$, $V_O = 1.4\text{ V}$	65	95		70	97		70	93		dB
I_{DD} Supply current	$V_O = V_{DD}/2$, $V_{IC} = V_{DD}/2$, No load		2.7	6.4		0.04	0.068		0.42	1.12	mA

NOTES: 4. The typical values of input bias current and input offset current below 5 pA were determined mathematically.

5. This range also applies to each input individually.

6. For low-bias mode, $R_L = 1\text{ M}\Omega$, for medium-bias mode, $R_L = 100\text{ k}\Omega$, and for high-bias mode, $R_L = 10\text{ k}\Omega$.

operating characteristics, $V_{DD} = 5\text{ V}$, $T_A = 25^\circ\text{C}$

PARAMETER	TEST CONDITIONS		TLC254Y			TLC25L4Y			TLC25M4Y			UNIT
			MIN	TYP	MAX	MIN	TYP	MAX	MIN	TYP	MAX	
SR Slew rate at unity gain	$C_L = 20\text{ pF}$, See Note 6	$V_I(PP) = 1\text{ V}$		3.6			0.03			0.43		V/ μs
		$V_I(PP) = 2.5\text{ V}$		2.9			0.03			0.40		
V_n Equivalent input noise voltage	$f = 1\text{ kHz}$, $R_S = 20\ \Omega$			2.5			70			32		nV/ $\sqrt{\text{Hz}}$
B_{OM} Maximum output-swing bandwidth	$V_O = V_{OH}$, $R_L = 10\text{ k}\Omega$	$C_L = 20\text{ pF}$		320			5			55		kHz
B_1 Unity-gain bandwidth	$V_I = 10\text{ mV}$, $C_L = 20\text{ pF}$			1.7			0.085			0.525		MHz
ϕ_m Phase margin	$f = B_1$, $C_L = 20\text{ pF}$	$V_I = 10\text{ mV}$		46°			34°			40°		

NOTE 6: For low-bias mode, $R_L = 1\text{ M}\Omega$, for medium-bias mode, $R_L = 100\text{ k}\Omega$, and for high-bias mode, $R_L = 10\text{ k}\Omega$.



PARAMETER MEASUREMENT INFORMATION

single-supply versus split-supply test circuits

Because the TLC25_4, TLC25_4A, and TLC25_4B are optimized for single-supply operation, circuit configurations used for the various tests often present some inconvenience since the input signal, in many cases, must be offset from ground. This inconvenience can be avoided by testing the device with split supplies and the output load tied to the negative rail. A comparison of single-supply versus split-supply test circuits is shown below. The use of either circuit gives the same result.

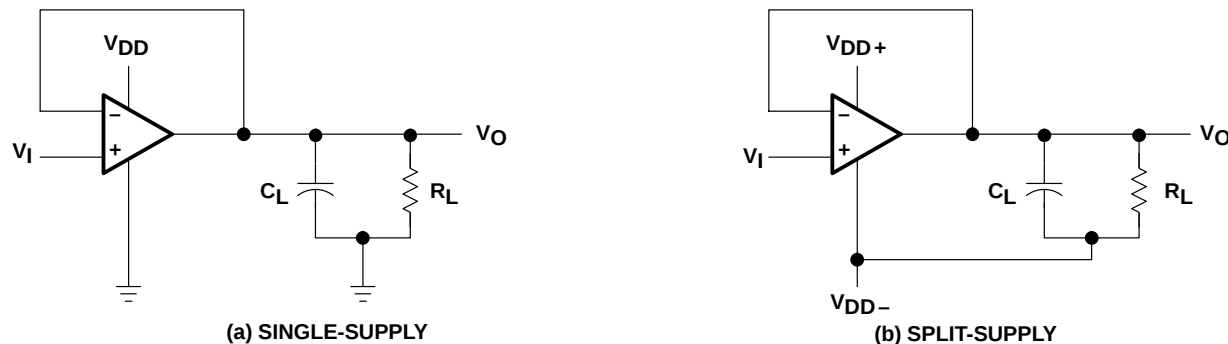


Figure 1. Unity-Gain Amplifier

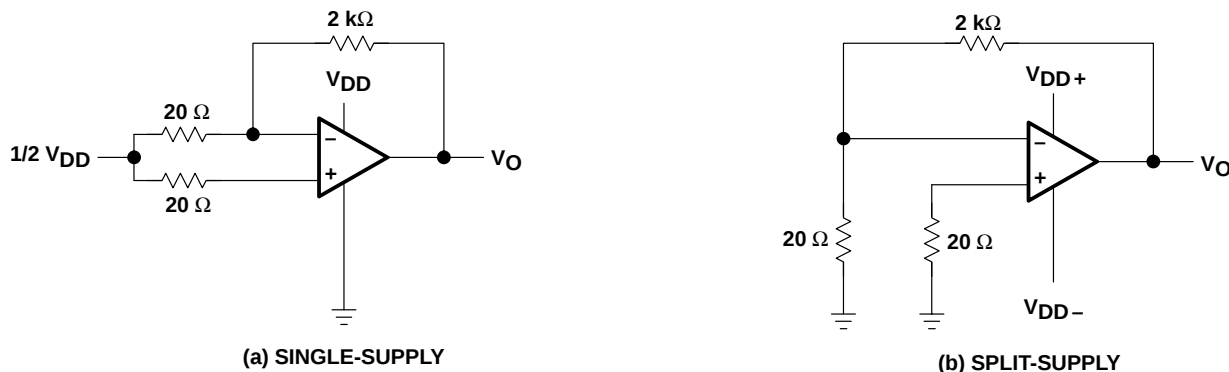


Figure 2. Noise-Test Circuit

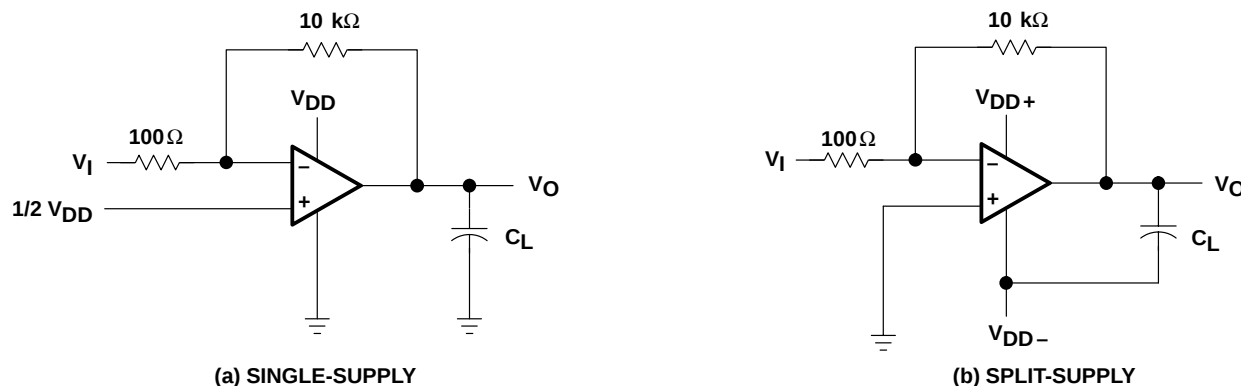


Figure 3. Gain-of-100 Inverting Amplifier

**TLC254, TLC254A, TLC254B, TLC254Y, TLC25L4, TLC25L4A, TLC25L4B
TLC25L4Y, TLC25M4, TLC25M4A, TLC25M4B, TLC25M4Y
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TYPICAL CHARACTERISTICS

Table of Graphs

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A_{VD}	Large-signal differential voltage amplification	Low bias vs Frequency	6
		Medium bias vs Frequency	7
		High bias vs Frequency	8
	Phase shift	Low bias vs Frequency	6
		Medium bias vs Frequency	7
		High bias vs Frequency	8

**SUPPLY CURRENT
vs
SUPPLY VOLTAGE**

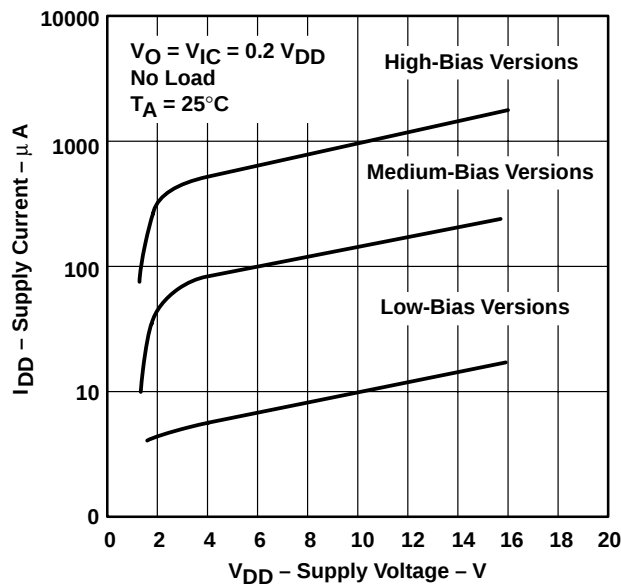


Figure 4

**SUPPLY CURRENT
vs
FREE-AIR TEMPERATURE**

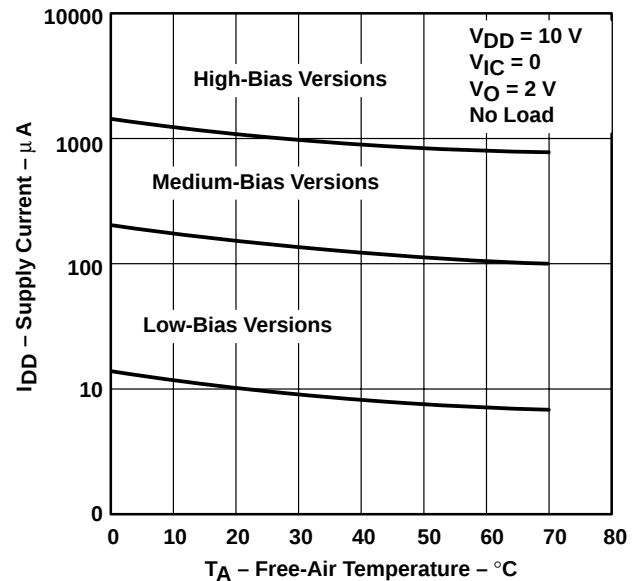


Figure 5

TYPICAL CHARACTERISTICS

LOW-BIAS LARGE-SIGNAL DIFFERENTIAL VOLTAGE AMPLIFICATION AND PHASE SHIFT

VS
FREQUENCY

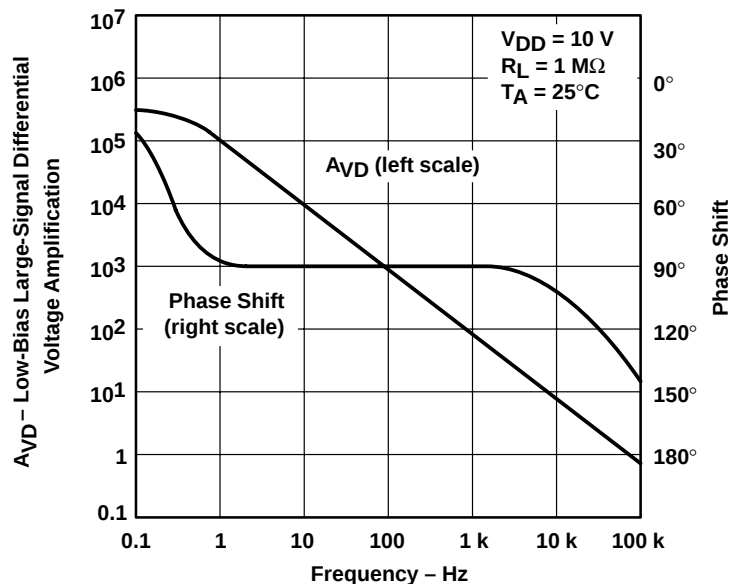


Figure 6

MEDIUM-BIAS LARGE-SIGNAL DIFFERENTIAL VOLTAGE AMPLIFICATION AND PHASE SHIFT

VS
FREQUENCY

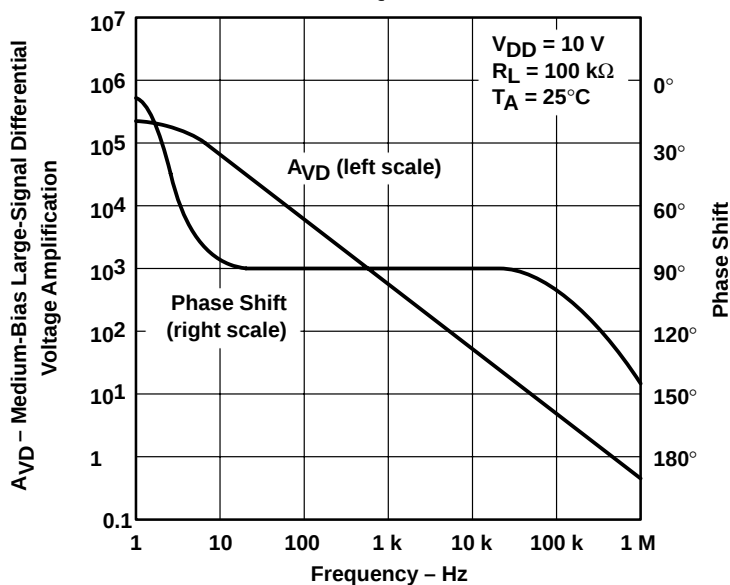


Figure 7

TYPICAL CHARACTERISTICS

HIGH-BIAS LARGE-SIGNAL DIFFERENTIAL VOLTAGE AMPLIFICATION AND PHASE SHIFT VS FREQUENCY

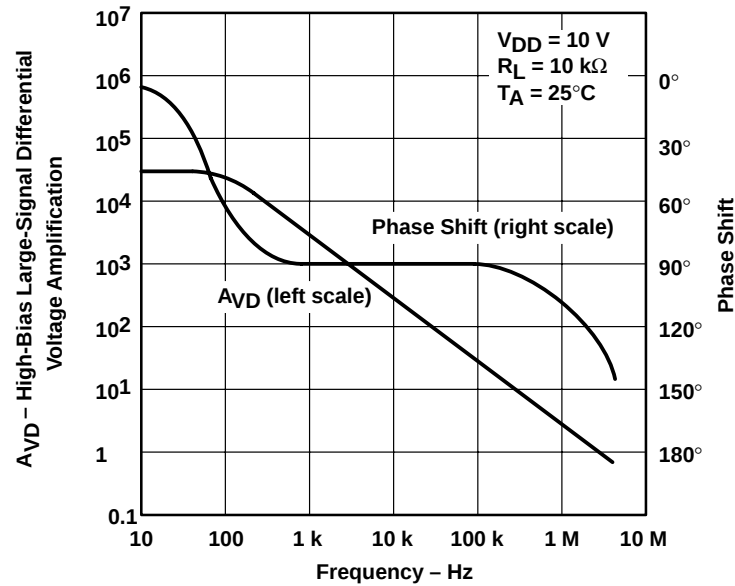


Figure 8

APPLICATION INFORMATION

latch-up avoidance

Junction-isolated CMOS circuits have an inherent parasitic PNP structure that can function as an SCR. Under certain conditions, this SCR may be triggered into a low-impedance state, resulting in excessive supply current. To avoid such conditions, no voltage greater than 0.3 V beyond the supply rails should be applied to any pin. In general, the operational amplifiers supplies should be established simultaneously with, or before, application of any input signals.

output stage considerations

The amplifier's output stage consists of a source-follower-connected pullup transistor and an open-drain pulldown transistor. The high-level output voltage (V_{OH}) is virtually independent of the I_{DD} selection and increases with higher values of V_{DD} and reduced output loading. The low-level output voltage (V_{OL}) decreases with reduced output current and higher input common-mode voltage. With no load, V_{OL} is essentially equal to the potential of V_{DD-}/GND .

supply configurations

Even though the TLC25_4C series is characterized for single-supply operation, they can be used effectively in a split-supply configuration if the input common-mode voltage (V_{ICR}), output swing (V_{OL} and V_{OH}), and supply voltage limits are not exceeded.

circuit layout precautions

Whenever extremely high circuit impedances are used, care must be exercised in layout, construction, board cleanliness, and supply filtering to avoid hum and noise pickup as well as excessive dc leakages.

PACKAGING INFORMATION

Orderable part number	Status (1)	Material type (2)	Package Pins	Package qty Carrier	RoHS (3)	Lead finish/ Ball material (4)	MSL rating/ Peak reflow (5)	Op temp (°C)	Part marking (6)
TLC254ACD	Active	Production	SOIC (D) 14	50 TUBE	Yes	NIPDAU	Level-1-260C-UNLIM	0 to 70	TLC254AC
TLC254ACD.A	Active	Production	SOIC (D) 14	50 TUBE	Yes	NIPDAU	Level-1-260C-UNLIM	0 to 70	TLC254AC
TLC254BCD	Active	Production	SOIC (D) 14	50 TUBE	Yes	NIPDAU	Level-1-260C-UNLIM	0 to 70	TLC254BC
TLC254BCD.A	Active	Production	SOIC (D) 14	50 TUBE	Yes	NIPDAU	Level-1-260C-UNLIM	0 to 70	TLC254BC
TLC254BCN	Active	Production	PDIP (N) 14	25 TUBE	Yes	NIPDAU	N/A for Pkg Type	0 to 70	TLC254BCN
TLC254BCN.A	Active	Production	PDIP (N) 14	25 TUBE	Yes	NIPDAU	N/A for Pkg Type	0 to 70	TLC254BCN
TLC254CD	Active	Production	SOIC (D) 14	50 TUBE	Yes	NIPDAU	Level-1-260C-UNLIM	0 to 70	TLC254C
TLC254CD.A	Active	Production	SOIC (D) 14	50 TUBE	Yes	NIPDAU	Level-1-260C-UNLIM	0 to 70	TLC254C
TLC254CN	Active	Production	PDIP (N) 14	25 TUBE	Yes	NIPDAU	N/A for Pkg Type	0 to 70	TLC254CN
TLC254CN.A	Active	Production	PDIP (N) 14	25 TUBE	Yes	NIPDAU	N/A for Pkg Type	0 to 70	TLC254CN
TLC254CNE4	Active	Production	PDIP (N) 14	25 TUBE	Yes	NIPDAU	N/A for Pkg Type	0 to 70	TLC254CN
TLC25L4BCD	Active	Production	SOIC (D) 14	50 TUBE	Yes	NIPDAU	Level-1-260C-UNLIM	0 to 70	25L4BC
TLC25L4BCD.A	Active	Production	SOIC (D) 14	50 TUBE	Yes	NIPDAU	Level-1-260C-UNLIM	0 to 70	25L4BC
TLC25L4CD	Active	Production	SOIC (D) 14	50 TUBE	Yes	NIPDAU	Level-1-260C-UNLIM	0 to 70	TLC25L4C
TLC25L4CD.A	Active	Production	SOIC (D) 14	50 TUBE	Yes	NIPDAU	Level-1-260C-UNLIM	0 to 70	TLC25L4C
TLC25M4CD	Active	Production	SOIC (D) 14	50 TUBE	Yes	NIPDAU	Level-1-260C-UNLIM	0 to 70	TLC25M4C
TLC25M4CD.A	Active	Production	SOIC (D) 14	50 TUBE	Yes	NIPDAU	Level-1-260C-UNLIM	0 to 70	TLC25M4C
TLC25M4CN	Active	Production	PDIP (N) 14	25 TUBE	Yes	NIPDAU	N/A for Pkg Type	0 to 70	TLC25M4CN
TLC25M4CN.A	Active	Production	PDIP (N) 14	25 TUBE	Yes	NIPDAU	N/A for Pkg Type	0 to 70	TLC25M4CN

⁽¹⁾ **Status:** For more details on status, see our [product life cycle](#).

⁽²⁾ **Material type:** When designated, preproduction parts are prototypes/experimental devices, and are not yet approved or released for full production. Testing and final process, including without limitation quality assurance, reliability performance testing, and/or process qualification, may not yet be complete, and this item is subject to further changes or possible discontinuation. If available for ordering, purchases will be subject to an additional waiver at checkout, and are intended for early internal evaluation purposes only. These items are sold without warranties of any kind.

⁽³⁾ **RoHS values:** Yes, No, RoHS Exempt. See the [TI RoHS Statement](#) for additional information and value definition.

⁽⁴⁾ **Lead finish/Ball material:** Parts may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

⁽⁵⁾ **MSL rating/Peak reflow:** The moisture sensitivity level ratings and peak solder (reflow) temperatures. In the event that a part has multiple moisture sensitivity ratings, only the lowest level per JEDEC standards is shown. Refer to the shipping label for the actual reflow temperature that will be used to mount the part to the printed circuit board.

⁽⁶⁾ **Part marking:** There may be an additional marking, which relates to the logo, the lot trace code information, or the environmental category of the part.

Multiple part markings will be inside parentheses. Only one part marking contained in parentheses and separated by a "~" will appear on a part. If a line is indented then it is a continuation of the previous line and the two combined represent the entire part marking for that device.

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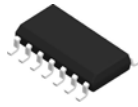
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TUBE

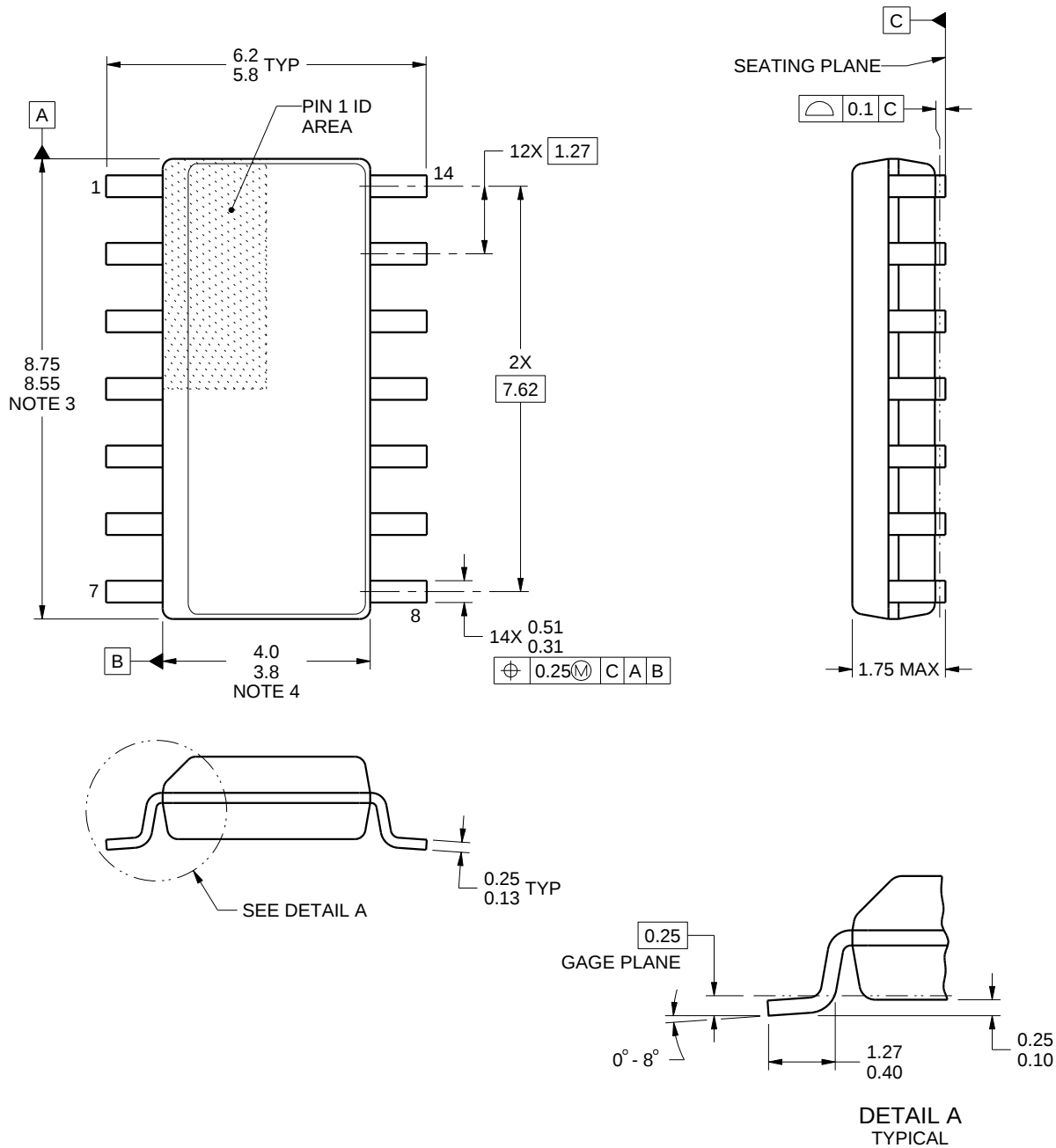


*All dimensions are nominal

Device	Package Name	Package Type	Pins	SPQ	L (mm)	W (mm)	T (μm)	B (mm)
TLC254ACD	D	SOIC	14	50	505.46	6.76	3810	4
TLC254ACD.A	D	SOIC	14	50	505.46	6.76	3810	4
TLC254BCD	D	SOIC	14	50	505.46	6.76	3810	4
TLC254BCD.A	D	SOIC	14	50	505.46	6.76	3810	4
TLC254BCN	N	PDIP	14	25	506	13.97	11230	4.32
TLC254BCN.A	N	PDIP	14	25	506	13.97	11230	4.32
TLC254CD	D	SOIC	14	50	505.46	6.76	3810	4
TLC254CD.A	D	SOIC	14	50	505.46	6.76	3810	4
TLC254CN	N	PDIP	14	25	506	13.97	11230	4.32
TLC254CN.A	N	PDIP	14	25	506	13.97	11230	4.32
TLC254CNE4	N	PDIP	14	25	506	13.97	11230	4.32
TLC25L4BCD	D	SOIC	14	50	505.46	6.76	3810	4
TLC25L4BCD.A	D	SOIC	14	50	505.46	6.76	3810	4
TLC25L4CD	D	SOIC	14	50	505.46	6.76	3810	4
TLC25L4CD.A	D	SOIC	14	50	505.46	6.76	3810	4
TLC25M4CD	D	SOIC	14	50	505.46	6.76	3810	4
TLC25M4CD.A	D	SOIC	14	50	505.46	6.76	3810	4
TLC25M4CN	N	PDIP	14	25	506	13.97	11230	4.32
TLC25M4CN.A	N	PDIP	14	25	506	13.97	11230	4.32

D0014A**PACKAGE OUTLINE****SOIC - 1.75 mm max height**

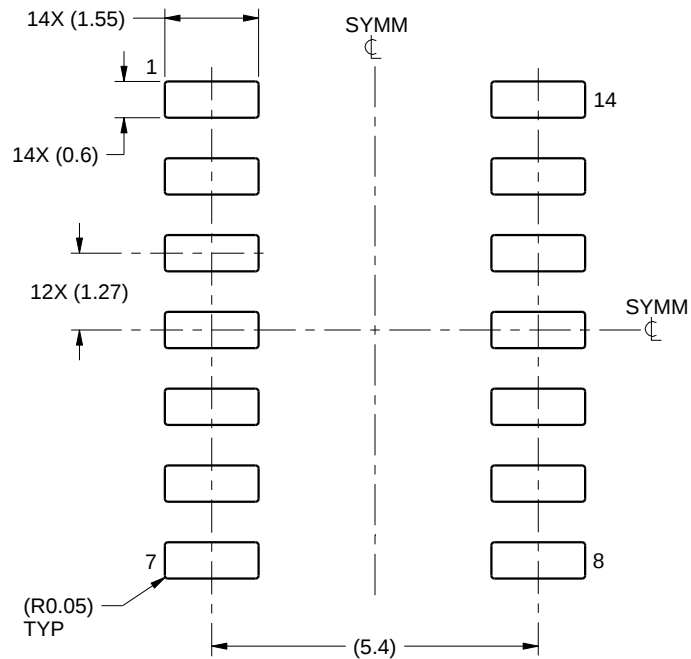
SMALL OUTLINE INTEGRATED CIRCUIT



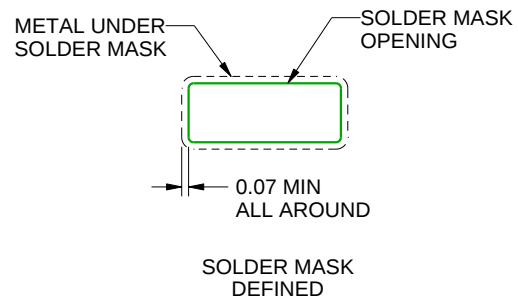
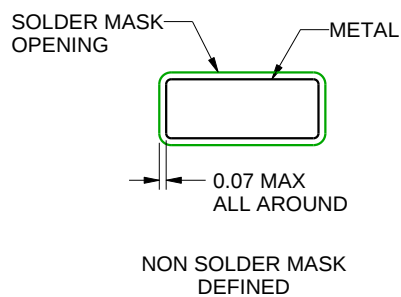
4220718/A 09/2016

NOTES:

1. All linear dimensions are in millimeters. Dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
2. This drawing is subject to change without notice.
3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0.15 mm, per side.
4. This dimension does not include interlead flash. Interlead flash shall not exceed 0.43 mm, per side.
5. Reference JEDEC registration MS-012, variation AB.



LAND PATTERN EXAMPLE
SCALE:8X



SOLDER MASK DETAILS

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NOTES: (continued)

6. Publication IPC-7351 may have alternate designs.

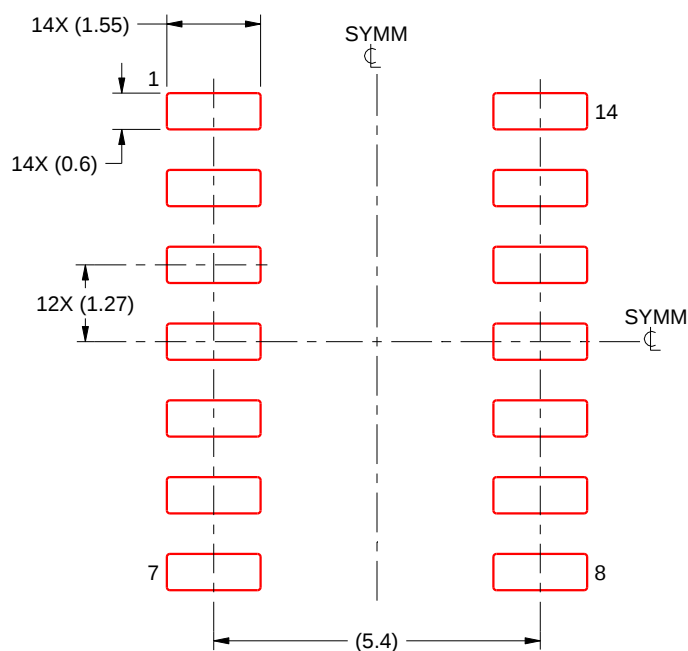
7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.

EXAMPLE STENCIL DESIGN

D0014A

SOIC - 1.75 mm max height

SMALL OUTLINE INTEGRATED CIRCUIT



SOLDER PASTE EXAMPLE
BASED ON 0.125 mm THICK STENCIL
SCALE:8X

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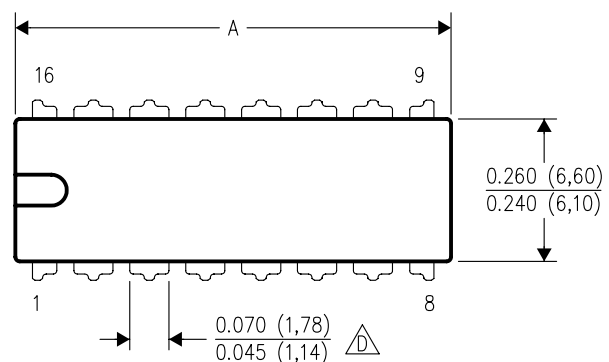
NOTES: (continued)

8. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
9. Board assembly site may have different recommendations for stencil design.

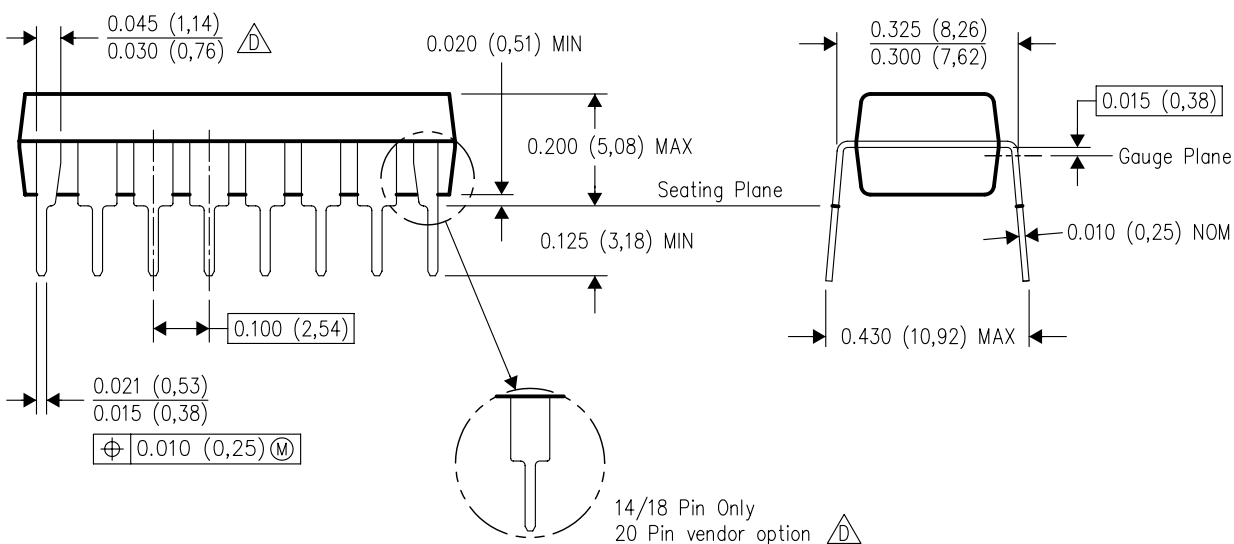
N (R-PDIP-T**)

16 PINS SHOWN

PLASTIC DUAL-IN-LINE PACKAGE



PINS ** DIM	14	16	18	20
A MAX	0.775 (19,69)	0.775 (19,69)	0.920 (23,37)	1.060 (26,92)
A MIN	0.745 (18,92)	0.745 (18,92)	0.850 (21,59)	0.940 (23,88)
MS-001 VARIATION	AA	BB	AC	AD



4040049/E 12/2002

NOTES:

- A. All linear dimensions are in inches (millimeters).
B. This drawing is subject to change without notice.
-  Falls within JEDEC MS-001, except 18 and 20 pin minimum body length (Dim A).
 The 20 pin end lead shoulder width is a vendor option, either half or full width.

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